

Abstracts

Rectified RF for High Power PIN Duplexing

H.S. Maddix and D.C. Broderick. "Rectified RF for High Power PIN Duplexing." 1979 MTT-S International Microwave Symposium Digest 79.1 (1979 [MWSYM]): 235-236.

Thin PIN diodes, loosely coupled to the main line, generate bias currents capable of driving high power PIN diodes in a low insertion loss duplexer with a capability greater than 300 kw peak - 5 kw average.

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